SCS220AE

SiC Schottky Barrier Diode

Datasheet

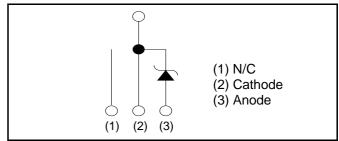
V_R	650V
I _F	20A
Q_C	31nC

●Outline TO-247

Features

- 1) Shorter recovery time
- 2) Reduced temperature dependence
- 3) High-speed switching possible

•Inner circuit



Applications

- PFC Boost Topology
- Secondary Side Rectification
- Data Center
- PV Power Conditioners

Packaging specifications

	gg opcomouncing	
	Packaging	Tube
	Reel size (mm)	-
Type	Tape width (mm)	-
Type	Basic ordering unit (pcs)	30
	Packing code	С
	Marking	SCS220AE

•Absolute maximum ratings $(T_i = 25^{\circ}C)$

Parameter		Symbol	Value	Unit
Reverse voltage (re	petitive peak)	V_{RM}	650	V
Reverse voltage (D	C)	V_{R}	650	V
Continuous forward	current (T _c = 129°C)	l _F 20		А
Surge non-			67	А
repetitive forward current	PW=10ms sinusoidal, T _j =150°C	I_{FSM}	53	А
	PW=10μs square, T _j =25°C		260	А
Repetitive peak forward current		I _{FRM}	81 ^{*1}	А
PW=10ms, T _j =25°C		۲.2 _۱ .	22	A ² s
i ² t value	PW=10ms, T _j =150°C	$\int i^2 dt$	14	A ² s
Total power disspation		P_{D}	130 *2	W
Junction temperature		T _j	175	°C
Range of storage temperature		T _{stg}	−55 to +175	°C

^{*1} T_c=100°C, T_i=150°C, Duty cycle=10% *2 T_c=25°C

•Electrical characteristics $(T_j = 25^{\circ}C)$

Parameter	meter Symbol Conditions -	Conditions	Values			Unit
Parameter		Min.	Тур.	Max.	Unit	
DC blocking voltage	V_{DC}	I _R =4.0mA	650	-	-	V
	V _F	I _F =20A,T _j =25°C	-	1.35	1.55	V
Forward voltage		I _F =20A,T _j =150°C	-	1.55	-	V
		I _F =20A,T _j =175°C	-	1.63	-	V
Reverse current	I _R	V _R =600V,T _j =25°C	-	4	400	μΑ
		V _R =600V,T _j =150°C	-	60	-	μΑ
		V _R =600V,T _j =175°C	-	140	-	μΑ
Total capacitance	С	V _R =1V,f=1MHz	-	730	-	pF
		V _R =600V,f=1MHz	-	74	-	pF
Total capacitive charge	Q _C	V _R =400V,di/dt=350A/μs	-	31	-	nC
Switching time	t _C	V _R =400V,di/dt=350A/μs	-	19	-	ns

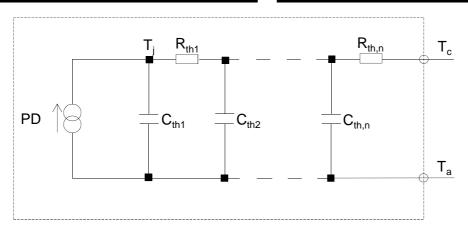
●Thermal characteristics

Parameter	Symbol	Conditions	Values			Unit
			Min.	Тур.	Max.	UIIIL
Thermal resistance	$R_{th(j-c)}$	-	-	0.92	1.1	°C/W

● Typical Transient Thermal Characteristics

Symbol	Value	Unit
R _{th1}	1.94E-01	
R _{th2}	7.23E-01	K/W
R _{th3}	5.52E-03	

Symbol	Value	Unit
C _{th1}	3.08E-03	
C _{th2}	8.36E-03	Ws/K
C _{th3}	1.03E+00	



•Electrical characteristic curves

Fig.1 V_F - I_F Characteristics

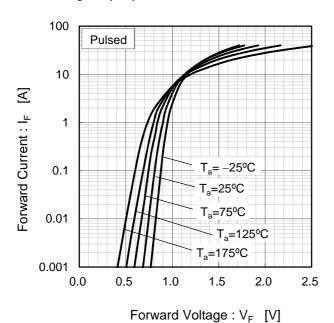
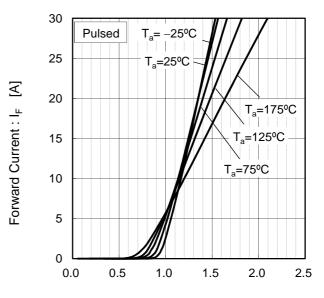


Fig.2 V_F - I_F Characteristics



Forward Voltage : V_F [V]

Fig.3 V_R - I_R Characteristics

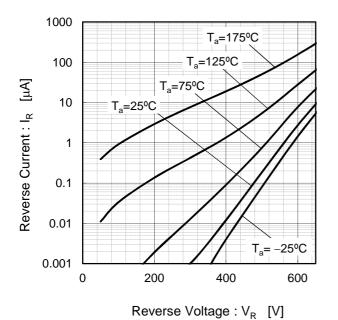
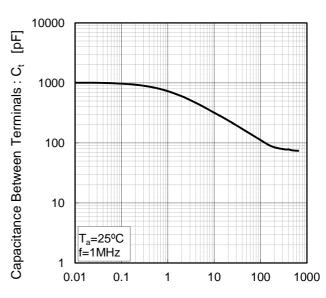


Fig.4 V_R - C_t Characteristics



Reverse Voltage : V_R [V]

•Electrical characteristic curves

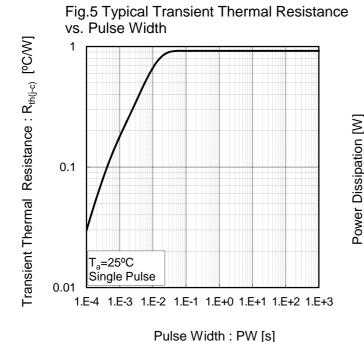
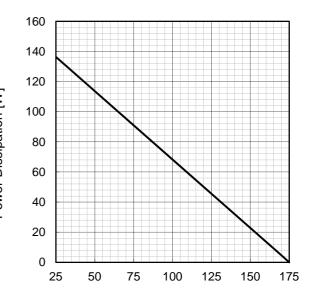


Fig.6 Power Dissipation

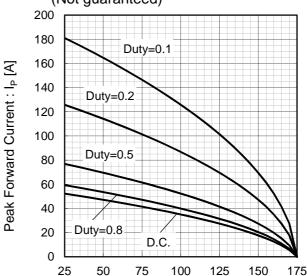


Case Temperature : T_c [°C]

Fig.7*3 Maximum peak forward current derating curve I_P - T_c 200 180 160 Peak Forward Current : Ip [A] 140 Duty=0.1 120 100 Duty=0.2 80 Duty=0.5 60 40 20 Duty=0.8 D.C. 0 25 50 75 100 125 150 175

Case Temperature : T_c [°C] *3 Based on max Vf, max R_{th(j-c)} Valid for switching of above 10kHz, excluding D.C. curve.

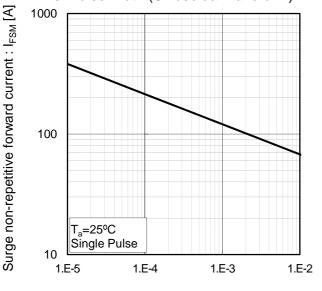
Fig.8*4 Typical peak forward current derating curve I_P - T_c (Not guaranteed)



Case Temperature : T_c [°C] *4 Based on typ Vf, typ R_{th(j-c)} Typical value, not guaranteed Valid for switching of above 10kHz, excluding D.C. curve

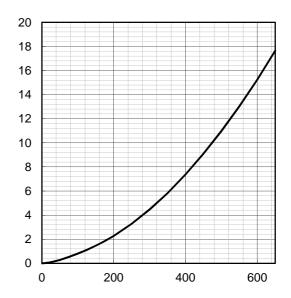
Electrical characteristic curves

Fig.9 Surge non-repetitive forward current vs. Pulse width (Sinusoidal waveform)



Pulse Width: PW [s]

Fig.10 Typical capacitance store energy

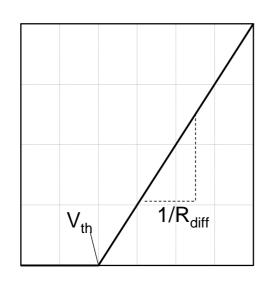


Capacitance stored energy ։ $\mathsf{E}_{\mathrm{C}}[\mu J]$

Reverse Voltage: V_R [V]

Symplified forward characteristic model

Fig.11 Equivalent forward current curve



Forward Voltage: V_F

$$V_F = V_{th} + R_{diff} I_F$$

$$\begin{aligned} &V_{th}\left(\ T_{j}\ \right) = a_{0} + a_{1} \, T_{j} \\ &R_{diff}\left(\ T_{j}\ \right) = b_{0} + b_{1} \, T_{j} + b_{2} \, T_{j}^{2} \end{aligned}$$

Symbol	Typical Value	Unit
a ₀	9.35E-01	V
a ₁	-1.12E-03	V/°C
b ₀	1.99E-02	Ω
b ₁	5.10E-05	Ω/°C
b ₂	5.40E-07	$\Omega/^{\circ}C^{2}$

 T_i in °C; -55 °C < T_i < °C; I_F < 40 A

Forward Current: IF

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